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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/591,987	01/24/2007	Takaki Yasuda	Q80398	6422
23373 SUGHRUE MI	7590 09/03/200 ON, PLLC	EXAMINER		
2100 PENNSYLVANIA AVENUE, N.W.			SINGAL, ANKUSH K	
SUITE 800 WASHINGTOI	TIE 800 ASHINGTON, DC 20037		ART UNIT	PAPER NUMBER
			2895	
			MAIL DATE	DELIVERY MODE
			09/03/2008	PAPER

## Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)			
	10/591,987	YASUDA ET AL.			
Office Action Summary	Examiner	Art Unit			
	ANKUSH k. SINGAL	2895			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period w  - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	lely filed the mailing date of this communication. (35 U.S.C. § 133).			
Status					
Responsive to communication(s) filed on <u>24 Ja</u> This action is <b>FINAL</b> . 2b)⊠ This     Since this application is in condition for allowar closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro				
Disposition of Claims					
4)  Claim(s) 1-4 is/are pending in the application.  4a) Of the above claim(s) is/are withdrav  5)  Claim(s) is/are allowed.  6)  Claim(s) 1-4 is/are rejected.  7)  Claim(s) is/are objected to.  8)  Claim(s) are subject to restriction and/or  Application Papers  9)  The specification is objected to by the Examine.  10)  The drawing(s) filed on 07 September 2006 is/a  Applicant may not request that any objection to the of  Replacement drawing sheet(s) including the correction.	r election requirement. r. ure: a)⊠ accepted or b)⊡ object drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).			
11)☐ The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.			
Priority under 35 U.S.C. § 119					
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>					
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 01/24/2007,09/07/2006.	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:	ite			

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## **DETAILED ACTION**

## Claim Objections

1. Claim 1 is objected to because of the following informalities: In claim 1 change "having" to "comprising" or "including". Appropriate correction is required.

## Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:
  - 1. Determining the scope and contents of the prior art.
  - 2. Ascertaining the differences between the prior art and the claims at issue.
  - 3. Resolving the level of ordinary skill in the pertinent art.
  - 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.
- 3. The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:
  - 1. Determining the scope and contents of the prior art.
  - 2. Ascertaining the differences between the prior art and the claims at issue.
  - 3. Resolving the level of ordinary skill in the pertinent art.
  - 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

4. Claims 1-4 are rejected under 35 U.S.C. 103(a) as being unpatentable over Johnson(US 6,975,660) in view of Nakatsu et al. (US 5,900,642).

Re. claim 1, Johnson discloses a pn. junction type Group III nitride semiconductor light-emitting device having a light-emitting layer of multiple quantum well structure in which well layers(120) and barrier layers(125) including Group III nitride semiconductors are alternately stacked periodically between an clad layer(108) and a clad layer(112) which are formed on a crystal substrate and which include Group III nitride semiconductors, wherein one end layer of the light-emitting layer is closest to and opposed to the clad layer, and the other end layer of the light-emitting layer is closest to and opposed to the p- type clad layer, both the one and the other end layers are barrier layers, and the other end layer is thicker than the barrier layer of the one end layer(Figure 12, columns 7-9).

Johnson does not teach the lower cladding layer being n-type and the upper cladding layer being p-type.

However, Nakatsu et al. teaches the lower cladding layer being n-type and the upper cladding layer being p-type (Figure 9) so that the isoelectronic level in the light emitting layer and the quantum level in the barrier layer will fulfill the resonance conditions.

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Therefore it would have been obvious for one with ordinary skill in the art at the time the invention was made to provide Johnson structure with the lower cladding layer being n-type and the upper cladding layer being p-type of Nakatsu et al. so that the isoelectronic level in the light emitting layer and the quantum level in the barrier layer will fulfill the resonance conditions.

Re. claims 2-4 as discussed above in claim 1, Johnson and Nakatsu et al. in combination disclose all the limitations as discussed above in claim 1 except each of the barrier layers has a thickness increased gradually from the one end layer toward the other end layer and the other end has an impurity concentration lower at its junction portion relative to the well layer, highest at its central portion and reduced gradually from the central portion toward the p-type clad layer and the other end layer has joined thereto a well layer which is not intentionally doped with impurities. However Johnson and Nakatsu et al. in combination disclosure for given conditions of the claimed invention, the claim range is considered to be an obvious matter of finding an optimum workable range for some chosen design requirement utilizing Johnson and Nakatsu et al. in combination method.

Note that it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves routine skill in the art. In re Aller, 105 USPQ 233.

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Any difference in the claimed invention and the prior art may be expected to result in some differences in properties. The issue is whether the properties differ to such an extent that the difference is really unexpected. In re Merck & Co.,800 F.2d 1091,231 USPQ 375 (Fed. Cir. 1986)

Any inquiry concerning this communication or earlier communications from the examiner should be directed to ANKUSH k. SINGAL whose telephone number is (571)270-1204. The examiner can normally be reached on monday-friday 7am-5pm EST.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Drew Richards can be reached on (571)272-1736. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Fernando L. Toledo/ Primary Examiner, Art Unit 2895

/Ankush k Singal/ Examiner, Art Unit 2895